# 74HC2G14-Q100; 74HCT2G14-Q100

# **Dual inverting Schmitt trigger**

Rev. 3 — 4 December 2023

Product data sheet

### 1. General description

The 74HC2G14-Q100; 74HCT2G14-Q100 is a dual inverter with Schmitt trigger inputs. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{\rm CC}$ . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- · Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
  - For 74HC2G14-Q100: CMOS level
  - For 74HCT2G14-Q100: TTL level
- High noise immunity
- · CMOS low power dissipation
- Balanced propagation delays
- · Unlimited input rise and fall times
- · Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards
  - JESD8C (2.7 V to 3.6 V)
  - JESD7A (2.0 V to 6.0 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

# 3. Applications

- Wave and pulse shaper for highly noisy environments
- · Astable multivibrators
- Monostable multivibrators

# 4. Ordering information

#### **Table 1. Ordering information**

Type number	Package	Package									
	Temperature range	Name	Description	Version							
74HC2G14GW-Q100	-40 °C to +125 °C	TSSOP6	F								
74HCT2G14GW-Q10	0		body width 1.25 mm								
74HC2G14GV-Q100	-40 °C to +125 °C	SC-74;	plastic surface-mounted package; 6 leads	SOT457							
74HCT2G14GV-Q10	<u>)</u>	TSOP6									



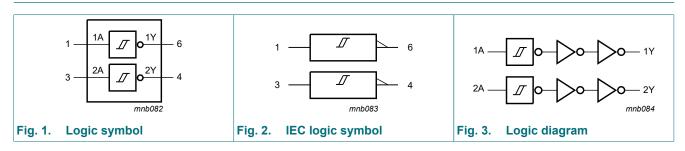
# 5. Marking

#### Table 2. Marking

Type number	Marking code[1]
74HC2G14GW-Q100	нк
74HCT2G14GW-Q100	тк
74HC2G14GV-Q100	H14
74HCT2G14GV-Q100	T14

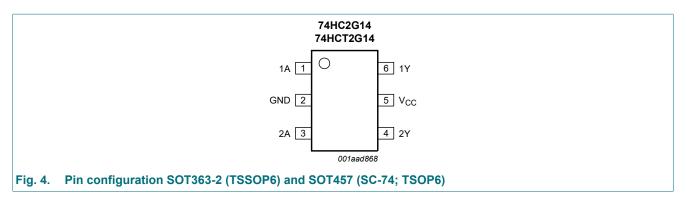
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 6. Functional diagram



# 7. Pinning information

### 7.1. Pinning



# 7.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
1A	1	data input
GND	2	ground (0 V)
2A	3	data input
2Y	4	data output
V <sub>CC</sub>	5	supply voltage
1Y	6	data output

# 8. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input	Output
nA	nY
L	Н
Н	L

# 9. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{O}$ < -0.5 V or $V_{O}$ > $V_{CC}$ + 0.5 V	[1]	-	±20	mA
I <sub>O</sub>	output current	$V_{O} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$	[1]	-	±25	mA
I <sub>CC</sub>	supply current		[1]	-	+50	mA
I <sub>GND</sub>	ground current		[1]	-	-50	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation		[2]	-	250	mW

<sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit				
74HC2G	74HC2G14-Q100									
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	V				
VI	input voltage		0	-	V <sub>CC</sub>	V				
Vo	output voltage		0	-	V <sub>CC</sub>	V				
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C				
74HCT2	G14-Q100									
V <sub>CC</sub>	supply voltage		4.5	5.0	5.5	V				
VI	input voltage		0	-	V <sub>CC</sub>	V				
Vo	output voltage		0	-	V <sub>CC</sub>	V				
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C				

<sup>[2]</sup> For SOT363-2 (TSSOP6) package: P<sub>tot</sub> derates linearly with 3.7 mW/K above 83 °C. For SOT457 (SC-74; TSOP6) package: P<sub>tot</sub> derates linearly with 4.1 mW/K above 89 °C.

# 11. Static characteristics

#### Table 7. Static characteristics for 74HC2G14-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	25 °C					
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	4.18	4.32	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	5.68	5.81	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	V
l <sub>l</sub>	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μA
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 $\mu$ A; $V_{CC}$ = 6.0 $V$	-	-	1.0	μA
Cı	input capacitance		-	2.0	-	pF
T <sub>amb</sub> = -	40 °C to +85 °C					
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 4.5 V	4.13	-	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V;	5.63	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	-	0.33	V
lį	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 $\mu$ A; $V_{CC}$ = 6.0 $V$	-	-	10.0	μΑ

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -4	10 °C to +125 °C					
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V;	5.2	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 $\mu$ A; $V_{CC}$ = 6.0 $V$	-	-	20.0	μA

#### Table 8. Static characteristics for 74HCT2G14-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	25 °C		-	1	'	
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	4.18	4.32	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	V
I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μΑ
I <sub>CC</sub>	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \mu A; V_{CC} = 5.5 \text{ V}$	-	-	1.0	μΑ
$\Delta I_{CC}$	additional supply current	$V_1 = V_{CC} - 2.1 \text{ V}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; I_O = 0  \mu\text{A}$	-	-	300	μΑ
C <sub>I</sub>	input capacitance		-	2.0	-	pF
T <sub>amb</sub> = -	40 °C to +85 °C			1		
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	4.13	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
l <sub>l</sub>	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 $\mu$ A; $V_{CC}$ = 5.5 $V$	-	-	10.0	μΑ
$\Delta I_{CC}$	additional supply current	$V_1 = V_{CC} - 2.1 \text{ V}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; I_O = 0  \mu\text{A}$	-	-	375	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -4	40 °C to +125 °C					
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 $\mu$ A; $V_{CC}$ = 5.5 $V$	-	-	20.0	μA
$\Delta I_{CC}$	additional supply current	$V_I = V_{CC}$ - 2.1 V; $V_{CC}$ = 4.5 V to 5.5 V; $I_O$ = 0 $\mu$ A	-	-	410	μA

# 12. Dynamic characteristics

#### Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

Symbol	Parameter	Conditions			25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	-
74HC2G	14-Q100					•					
t <sub>pd</sub>	propagation	nA to nY; see Fig. 5	[1]								
	delay	$V_{CC}$ = 2.0 V; $C_L$ = 50 pF		-	53	125	-	155	-	190	ns
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		-	16	25	-	31	-	38	ns
		$V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$		-	13	21	-	26	-	32	ns
t <sub>t</sub>	transition time	nY; see Fig. 5	[2]								
		$V_{CC}$ = 2.0 V; $C_L$ = 50 pF		-	20	75	-	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$		-	5	13	-	16	-	19	ns
C <sub>PD</sub>	power dissipation capacitance	V <sub>I</sub> = GND to V <sub>CC</sub>	[3]	-	10	-	-	-		-	pF
74HCT2	G14-Q100										
t <sub>pd</sub>	propagation	nA to nY; see Fig. 5	[1]								
	delay	V <sub>CC</sub> = 4.5 V; C <sub>L</sub> = 50 pF		-	21	32	-	40	-	48	ns
t <sub>t</sub>	transition time	nY; see Fig. 5	[2]								
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		-	6	15	-	19	-	22	ns
C <sub>PD</sub>	power dissipation capacitance	$V_{I}$ = GND to $V_{CC}$ - 1.5 V	[3]	-	10	-	-	-	-	-	pF

- [1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$
- [2] t<sub>t</sub> is the same as t<sub>TLH</sub> and t<sub>THL</sub>
   [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

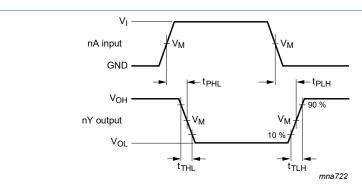
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

#### 12.1. Waveforms and test circuit



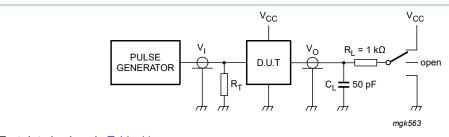
Measurement points are given in Table 10.

 $\ensuremath{V_{\text{OL}}}$  and  $\ensuremath{V_{\text{OH}}}$  are typical voltage output levels that occur with the output load.

Fig. 5. The data input (nA) to output (nY) propagation delays and output transition times

**Table 10. Measurement points** 

Туре	Input	Output		
	V <sub>M</sub>	V <sub>I</sub>	$t_r = t_f$	V <sub>M</sub>
74HC2G14-Q100	0.5V <sub>CC</sub>	GND to V <sub>CC</sub>	6.0 ns	0.5V <sub>CC</sub>
74HCT2G14-Q100	1.3 V	GND to 3.0 V	6.0 ns	1.3 V



Test data is given in Table 11.

Definitions test circuit:

R<sub>L</sub> = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

Fig. 6. Test circuit for measuring switching times

Table 11. Test data

Туре	Input	Test	
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	t <sub>PHL</sub> , t <sub>PLH</sub>
74HC2G14-Q100	GND to V <sub>CC</sub>	6 ns	open
74HCT2G14-Q100	GND to 3.0 V	6 ns	open

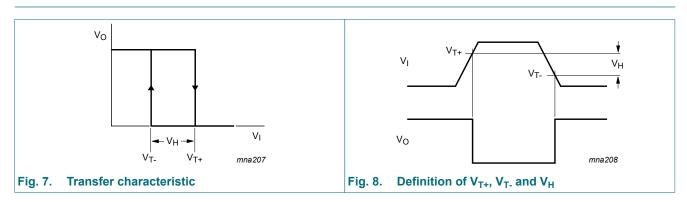
# 13. Transfer characteristics

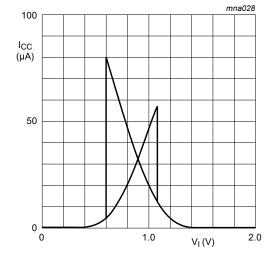
#### **Table 12. Transfer characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

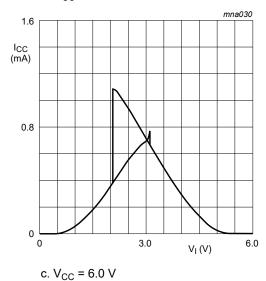
Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC2G	14-Q100			'		1				
	positive-going	see <u>Fig. 7</u> , <u>Fig. 8</u>								
	threshold voltage	V <sub>CC</sub> = 2.0 V	1.00	1.18	1.50	1.00	1.50	1.00	1.50	V
		V <sub>CC</sub> = 4.5 V	2.30	2.60	3.15	2.30	3.15	2.30	3.15	V
		V <sub>CC</sub> = 6.0 V	3.00	3.46	4.20	3.00	4.20	3.00	4.20	V
V <sub>T</sub> . negative-going threshold voltage		see Fig. 7, Fig. 8								
	threshold voltage	V <sub>CC</sub> = 2.0 V	0.30	0.60	0.90	0.30	0.90	0.30	0.90	V
		V <sub>CC</sub> = 4.5 V	1.13	1.47	2.00	1.13	2.00	1.13	2.00	V
		V <sub>CC</sub> = 6.0 V	1.50	2.06	2.60	1.50	2.60	1.50	2.60	V
V <sub>H</sub> hysteresis voltaç	hysteresis voltage	(V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Fig. 7</u> , <u>Fig. 8</u> and <u>Fig. 9</u>								
		V <sub>CC</sub> = 2.0 V	0.30	0.60	1.00	0.30	1.00	0.30	1.00	V
		V <sub>CC</sub> = 4.5 V	0.60	1.13	1.40	0.60	1.40	0.60	1.40	V
		V <sub>CC</sub> = 6.0 V	0.80	1.40	1.70	0.80	1.70	0.80	1.70	V
<b>74HCT2</b>	G14-Q100									
	positive-going	see Fig. 7 and Fig. 8								
	hreshold voltage	V <sub>CC</sub> = 4.5 V	1.20	1.58	1.90	1.20	1.90	1.20	1.90	V
		V <sub>CC</sub> = 5.5 V	1.40	1.78	2.10	1.40	2.10	1.40	2.10	V
V <sub>T-</sub>	negative-going threshold voltage	see Fig. 7 and Fig. 8								
threshold volta		V <sub>CC</sub> = 4.5 V	0.50	0.87	1.20	0.50	1.20	0.50	1.20	V
		V <sub>CC</sub> = 5.5 V	0.60	1.11	1.40	0.60	1.40	0.60	1.40	V
V <sub>H</sub>	hysteresis voltage	(V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Fig. 7</u> , <u>Fig. 8</u> and <u>Fig. 10</u>								
		V <sub>CC</sub> = 4.5 V	0.40	0.71	-	0.40	-	0.40	-	V
		V <sub>CC</sub> = 5.5 V	0.40	0.67	-	0.40	-	0.40	-	V

# 14. Waveforms transfer characteristics

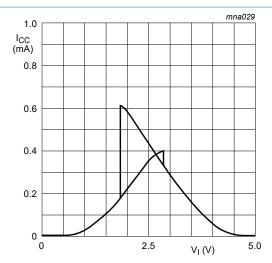






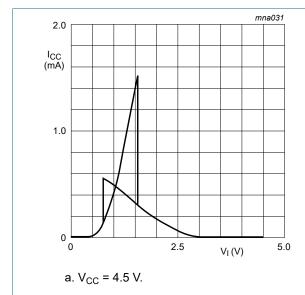


a.  $V_{CC} = 2.0 \text{ V}$ 



b. 
$$V_{CC} = 4.5 \text{ V}$$





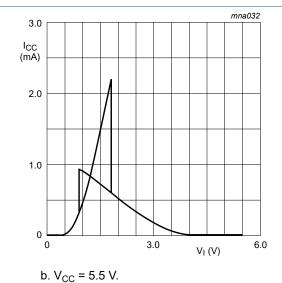


Fig. 10. Typical 74HCT2G14-Q100 transfer characteristics

# 15. Application information

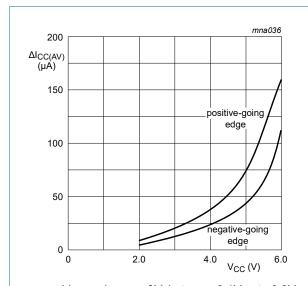
The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$  where:

- P<sub>add</sub> = additional power dissipation (μW);
- f<sub>i</sub> = input frequency (MHz);
- t<sub>r</sub> = input rise time (ns); 10 % to 90 %;
- t<sub>f</sub> = input fall time (ns); 90 % to 10 %;
- ΔI<sub>CC(AV)</sub> = average additional supply current (µA).

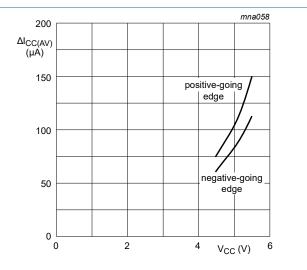
Δl<sub>CC(AV)</sub> differs with positive or negative input transitions, as shown in Fig. 11 and Fig. 12.

An example of a relaxation circuit using the 74HC2G14-Q100; 74HCT2G14-Q100 is shown in Fig. 13.



Linear change of V<sub>I</sub> between 0.1V<sub>CC</sub> to 0.9V<sub>CC</sub>

Fig. 11.  $\Delta I_{CC(AV)}$  as a function of  $V_{CC}$  for 74HC2G14-Q100



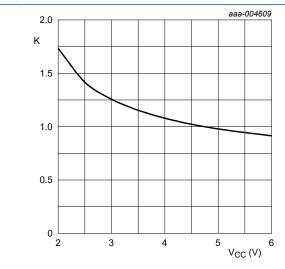
Linear change of  $V_{\text{I}}$  between  $0.1V_{\text{CC}}$  to  $0.9V_{\text{CC}}$ 

Fig. 12.  $\Delta I_{CC(AV)}$  as a function of  $V_{CC}$  for 74HCT2G14-Q100

For 74HC2G14-Q100:  $f = \frac{1}{T} \approx \frac{1}{0.8 \times \text{RC}}$ For 74HCT2G14-Q100:  $f = \frac{1}{T} \approx \frac{1}{0.67 \times \text{RC}}$ 

For K-factor, see Fig. 14 or Fig. 15

#### Fig. 13. Relaxation oscillator



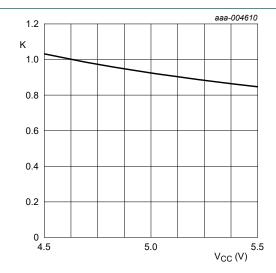


Fig. 14. K-factor for 74HC2G14-Q100 Fig. 15. K-facto

Fig. 15. K-factor for 74HCT2G14-Q100

# 16. Package outline

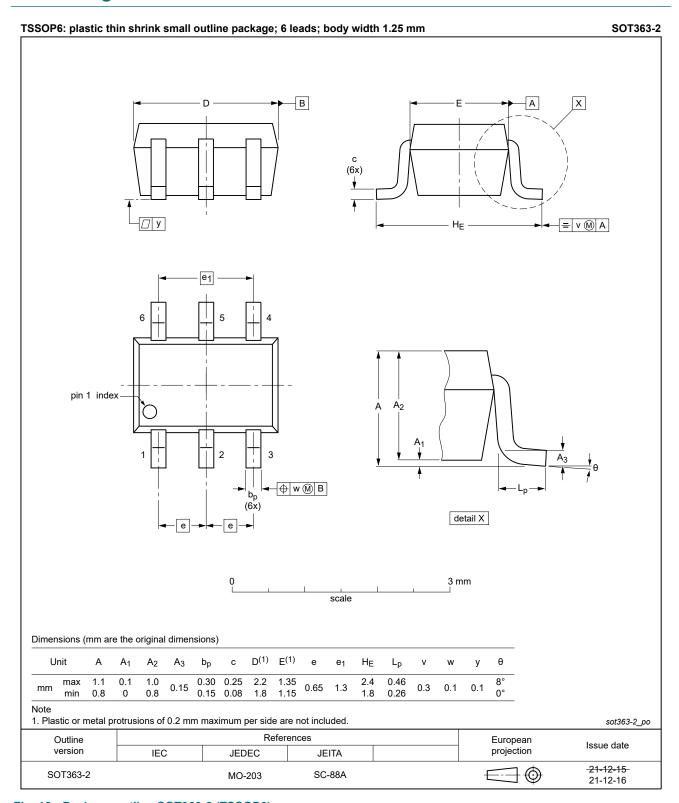


Fig. 16. Package outline SOT363-2 (TSSOP6)

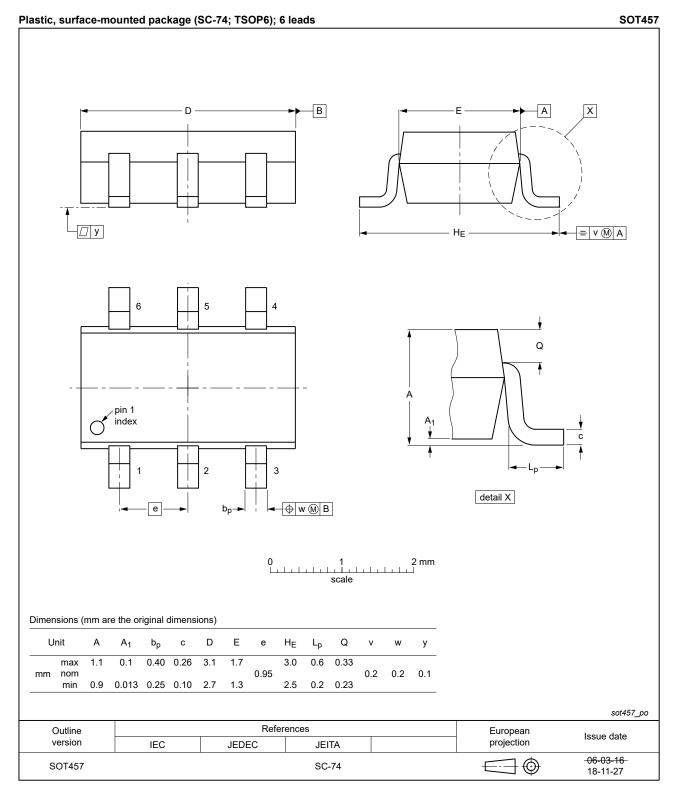


Fig. 17. Package outline SOT457 (SC-74; TSOP6)

# 17. Abbreviations

#### **Table 13. Abbreviations**

Acronym	Description
CDM	Charge Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

# 18. Revision history

#### **Table 14. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT2G14_Q100 v.3	20231204	Product data sheet	-	74HC_HCT2G14_Q100 v.2			
Modifications:	Section 2: E	Section 2: ESD specification updated according to the latest JEDEC standard.					
74HC_HCT2G14_Q100 v.2	20220128	Product data sheet	-	74HC_HCT2G14_Q100 v.1			
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6).</li> <li>Section 2 updated.</li> <li>Section 9: Derating values for P<sub>tot</sub> total power dissipation updated.</li> <li>Fig. 17: Package outline drawing SOT457 (SC-74; TSOP6) updated.</li> </ul>						
74HC_HCT2G14_Q100 v.1	20140320	Product data sheet	-	-			

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#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

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